



Substitute for form 1449A/B/PTO		Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)		Application Number	09/391,472
		Filing Date	September 8, 1999
		First Named Inventor	Naoto Jikutani
		Art Unit	1765
		Prior Examiner Name	R. Kunemund
Sheet 1 of 1	Attorney Docket Number	R2184.0052/P052-A	

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ³ (if known)			
A	AA	4,745,612 A	05/1988	Hayakawa et al.	
	AB	5,383,211 A	01/1995	Van de Walle et al.	
	AC	5,585,649 A	12/1996	Ishikawa et al.	
	AD	6,150,677 A	11/2000	Tanaka et al.	

FOREIGN PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
A	AE	Ougazzaden et al., "Metal Organic Vapor Phase Epitaxy Growth of GaN on GaAs Using Dimethylhydrazine and Tertiarybutylarsine," Applied Physics Letters, Vol. 70, No. 21, May 26, 1997, pp. 2861-2863	

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